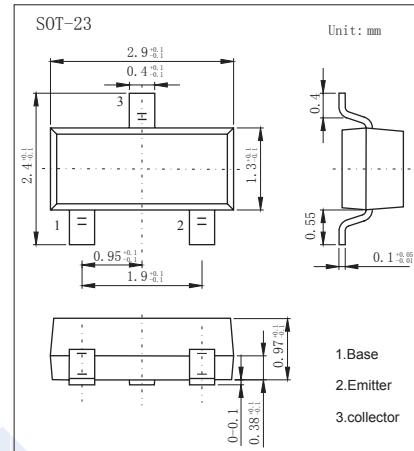


NPN Transistors**BFS17 (KFS17)****■ Features**

- Collector Current Capability $I_c=25\text{mA}$
- Collector Emitter Voltage $V_{CEO}=15\text{V}$

**■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$**

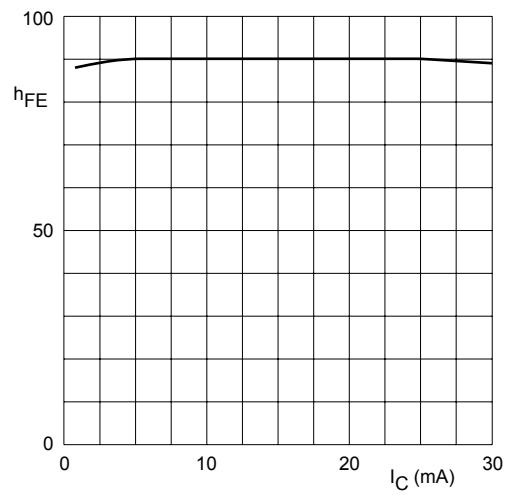
Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CBO}	25	V
Collector - Emitter Voltage	V_{CEO}	15	
Emitter - Base Voltage	V_{EBO}	2.5	
Collector Current - Continuous	I_c	25	mA
Collector Current - Pulse	I_{CP}	50	
Collector Power Dissipation	P_c	300	mW
Thermal Resistance From Junction to Soldering Point	$R_{\theta JS}$	260	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to 150	

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V_{CBO}	$I_c= 100 \mu\text{A}, I_E= 0$	25			V
Collector-emitter breakdown voltage	V_{CEO}	$I_c= 1 \text{ mA}, I_B= 0$	15			
Emitter-base breakdown voltage	V_{EBO}	$I_E= 100 \mu\text{A}, I_c= 0$	2.5			
Collector-base cut-off current	I_{CBO}	$V_{CB}= 25 \text{ V}, I_E= 0$			100	nA
Emitter cut-off current	I_{EBO}	$V_{EB}= 2.5\text{V}, I_c=0$			100	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_c=25 \text{ mA}, I_B=2.5 \text{ mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_c=25 \text{ mA}, I_B=2.5\text{mA}$			1.2	
DC current gain	h_{FE}	$V_{CE}= 1\text{V}, I_c= 2\text{mA}$	25	90		
		$V_{CE}= 1\text{V}, I_c= 25\text{mA}$	25	90		
Collector Capacitance	C_C	$V_{CB}= 10\text{V}, I_E=i_E= 0, f=1\text{MHz}$			1.5	pF
Emitter Capacitance	C_E	$V_{EB}= 0.5\text{V}, I_c=i_c= 0, f=1\text{MHz}$			2	
Feedback Capacitance	C_{re}	$V_{CE}= 5\text{V}, I_c=1\text{mA}, f=1\text{MHz}$			0.65	
Noise Figure	NF	$V_{CE}= 5\text{V}, I_c= 2\text{mA}, R_s=50\Omega, f=500\text{MHz}$			4.5	dB
Transition frequency	f_T	$V_{CE}= 5\text{V}, I_c= 2\text{mA}, f=500\text{MHz}$			1	
		$V_{CE}= 5\text{V}, I_c= 25 \text{ mA}, f=500\text{MHz}$			1.6	GHz

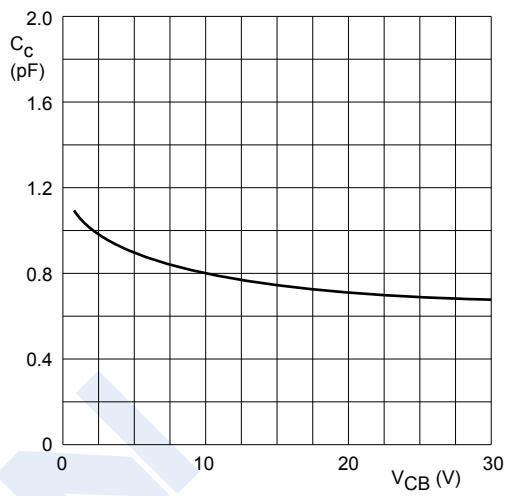
■ Marking

Marking	E1*
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NPN Transistors**BFS17 (KFS17)****■ Typical Characteristics**

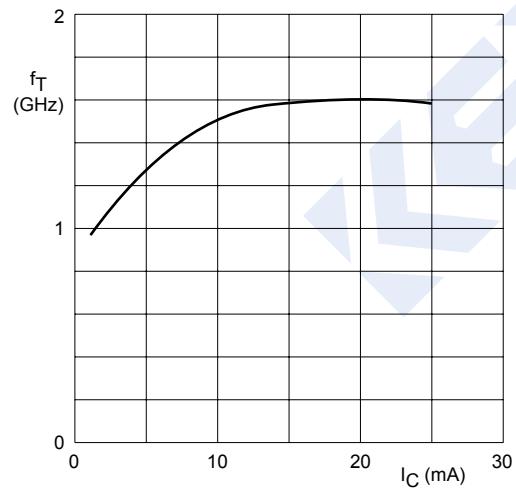
$V_{CE} = 1$ V; $T_j = 25$ °C.

Fig.2 DC current gain as a function of collector current.



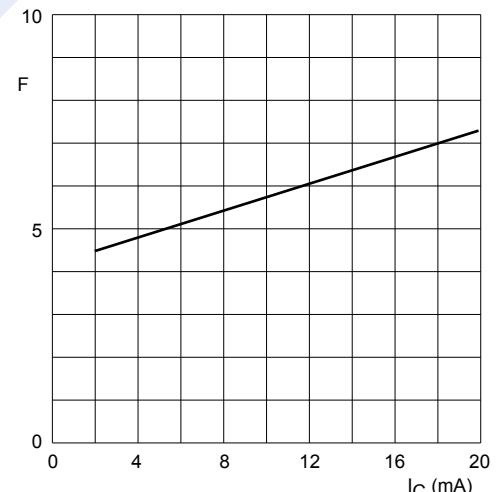
$I_E = i_e = 0$; $f = 1$ MHz; $T_j = 25$ °C.

Fig.3 Collector capacitance as a function of collector-base voltage.



$V_{CE} = 5$ V; $f = 500$ MHz; $T_j = 25$ °C.

Fig.4 Transition frequency as a function of collector current.



$V_{CE} = 5$ V; $R_S = 50$ Ω; $f = 500$ MHz; $T_j = 25$ °C.

Fig.5 Minimum noise figure as a function of collector current.